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**COMP 3 - 6 (RC)** 

P.T.O.

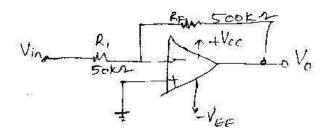
# S.E. (Computer) (Semester – III) (RC) Examination, May/June 2014 INTEGRATED ELECTRONICS

Duration : 3 Hours Total Marks : 100

Instructions: 1) Attempt any 5, choosing atleast one from each Module.
2) Assume any data, if necessary.

#### MODULE - 1

a) With the help of a diagram explain the working of an integrator. What are the drawbacks and how are they overcome?
 b) What is a feedback? Explain the types of feedback. Which type is used in linear applications?
 c) Write a note on the freq. response of a opamp.
 d) If an input signal of – 0.5v were applied, determine the output voltage for the circuit shown below:



d) Draw the block diagram of a instrumentation amplifier.

a) Explain the working of a noninverting comparator.
b) Define the following:
 input offset voltage, slew rate, SVRR.
c) Draw the circuit diagram of voltage series feedback amplifier and derive an expression for
 i) Voltage gain
 ii) Input impedance
 iii) Output impedance
 iv) Total output offset voltage.

### MODULE-2

-2-

3. a) Write a note on the following:

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- i) Phase detector
- ii) Low pass filter.
- b) Draw a circuit of a voltage regulator based on IC 723 for a higher current rating and a higher output voltage (greater than 10V).
- 6
- c) Explain the working of IC 555 as a monostable multivibrator.
- 6

4. a) Explain the various applications of PLL.

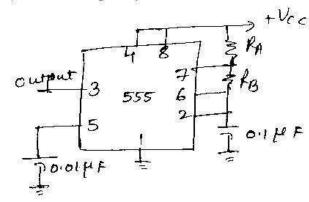
- 6-
- b) Design a low voltage regulator for the following specifications.

$$V_0 = 5V$$
,  $I_m = 50$  mA,  $V_{in} = 10V$ ,  $T_A = 25$ °C,  $V_{sense} = 6.65V$ .

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c) In fig.  $R_A = 2.2k\Omega$ ,  $R_B = 3.9k\Omega$  and  $C = 0.1\,\mu$  F. Find out the pulse width of positive and negative pulses. Also calculate the free running frequency.

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d) Briefly, explain the block diagram of IC 555 timer.

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## MODULE-3

- 5. a) Explain propagation time delay and noise margin w.r.t. digital logic.
- 5
- b) Describe the 3-input HTL NAND gate with fan-out of N similar gates along with a neat circuit diagram and give its advantages.

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		3- COMP 3 - 6 (R	C)
	c)	List the characteristics of a CMOS circuit and explain CMOS inverter and verify the operation is performed for all input combinations.	7
6.	a)	Along with a circuit diagram 3-input TTL NAND gate, explain its operation.	8
	b)	Mention the advantages of ECL gate and give the symbol for ECL OR/NOR gate.	6
	c)	Give advantages and disadvantages of DTL gate and draw the circuit diagram for 3-input DTL NAND gate.	6
		MODULE - 4	
7.	<b>a</b> )	Explain the successive approximation method of analog to digital conversion. Discuss the working of ADC using this method.	8
	b)	Define the following specifications of data converters with suitable example :  i) Resolution  ii) Accuracy	8
		iii) Linearity error iv) Settling time.	
	c)	Mention the applications of A/D and D/A are used.	4
8.	a)	Explain the voltage to frequency converter and derive the necessary expressions for analog to digital conversion.	6
	b)	What is the resolution in volts of a 12 bit binary ladder DAC, if its full scale output voltage is + 10V and find the percentage resolution?	7
	c)	Explain the waveforms of dual-slope A/D converter and give its advantages and disadvantages.	7